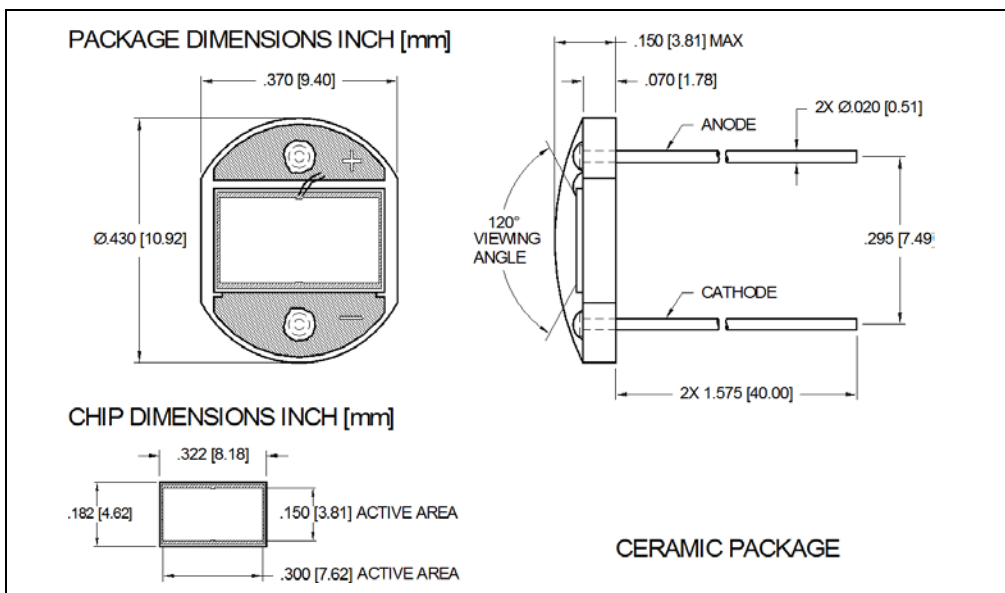




DESCRIPTION

The **PDB-C140** is a blue enhanced PIN silicon photodiode in a photoconductive mode, packaged in a ceramic package.

FEATURES

- Low Noise
- Blue Enhanced
- High Shunt Resistance
- High Response

RELIABILITY

Contact Luna for recommendations on specific test conditions and procedures.

APPLICATIONS

- Instrumentation
- Industrial
- Medical



ABSOLUTE MAXIMUM RATINGS

SYMBOL	MIN		MAX	UNITS	
Reverse Voltage	-	-	75	V	$T_a = 23^{\circ}\text{C}$ UNLESS OTHERWISE NOTED
Storage Temperature	-40	to	+100	$^{\circ}\text{C}$	-
Operating Temperature	-40	to	+100	$^{\circ}\text{C}$	-
Soldering Temperature*	-	-	+240	$^{\circ}\text{C}$	-

* 1/16 inch from case for 3 seconds max.

OPTO-ELECTRICAL PARAMETERS

$T_a = 23^\circ\text{C}$ UNLESS OTHERWISE NOTED

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNITS
Short Circuit Current	H=100 fc, 2850 K	300	350	-	μA
Dark Current	$V_R = 10\text{V}$	-	10	25	nA
Shunt Resistance	$V_R = 10\text{ mV}$	5	50	-	M Ω
Junction Capacitance	$V_R = 10\text{V}$, $f = 1\text{ MHz}$	-	200	-	pF
Spectral Application Range	Spot Scan	350	-	1100	nm
Responsivity	$\lambda = 450\text{nm}$ V, $V_R = 0\text{V}$	0.15	0.18	-	A/W
Breakdown Voltage	$I = 10\text{ }\mu\text{A}$	50	75	-	V
Noise Equivalent Power	$V_R = 10\text{V}$ @ $\lambda = 950\text{nm}$	-	9×10^{-13}	-	$\text{W}/\sqrt{\text{Hz}}$
Response Time**	$R_L = 50\Omega$, $V_R = 0\text{V}$	-	190	-	nS
	$R_L = 50\Omega$, $V_R = 10\text{V}$	-	13	-	

**Response time of 10% to 90% is specified at 660nm wavelength light.

TYPICAL PERFORMANCE

SPECTRAL RESPONSE

